



20A, 100V - 200V Dual Common Cathode Schottky Rectifiers

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition







MECHANICAL DATA

Case: TO-263AB (D²PAK)

Molding compound, UL flammability classification rating 94V-0

Moisture sensitivity level: level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified

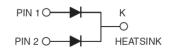
Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: As marked

Weight: 1.4 g (approximately)

TO-263AB (D²PAK)



PARAMETER	SYMBOL	MBRS	MBRS	MBRS	Unit
		20H100CT	20H150CT	20H200CT	J Oille
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V
Maximum RMS voltage	V_{RMS}	70	105	140	V
Maximum DC blocking voltage	V_{DC}	100	150	200	V
Maximum average forward rectified current	I _{F(AV)}		20		Α
Peak repetitive forward current (Rated VR, Square wave, 20KHz)	I _{FRM}	20			А
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150		А	
Peak repetitive reverse surge current (Note 1)	I _{RRM}	1 0.5		Α	
Maximum instantaneous forward voltage (Note 2)					
I _F =10A, T _J =25°C	V _F	0.85	0.88 0.75 0.97 0.85		V
I _F =10A, T _J =125°C		0.75			
I _F =20A, T _J =25°C		0.95			
I _F =20A, T _J =125°C		0.85			
T _J =25°C Maximum reverse current @ rated V _R		5		μA	
T _J =125°C	I _R	2			mA
Voltage rate of change (Rated V _R)	dV/dt	10000			V/µs
Typical thermal resistance	R _{θJC}	1.5			°C/W
Operating junction temperature range	TJ	- 55 to +175		°C	
Storage temperature range	T _{STG}	- 55 to +175			οС

Note 1: $tp = 2.0 \mu s$, 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle

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ORDERING INFORMATION					
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX ^(*)	PACKAGE	PACKING
MBRS20HxxxCT	Н	RN	G	D ² PAK	800 / 13" Paper reel
(Note 1)	11	MN	G		800 / 13" Plastic reel

Note 1: "xx" defines voltage from 100V (MBRS20H100CT) to 200V (MBRS20H200CT)

^{*:} Optional available

EXAMPLE					
PREFERRED P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
MBRS20H100CTHRNG	MBRS20H100CT	Н	RN	G	AEC-Q101 qualified Green compound

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

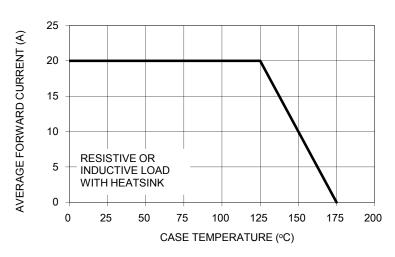


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

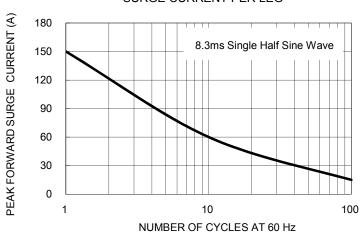


FIG. 3 TYPICAL FORWARD CHARACTERISTICS PER LEG

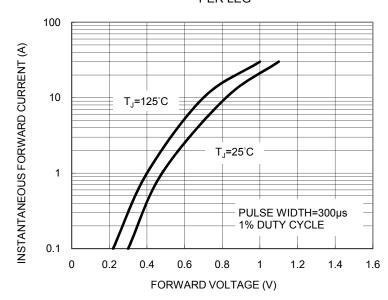


FIG. 4 TYPICAL REVERSE CHARACTERISTICS PER LEG

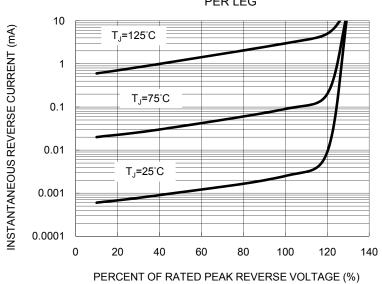
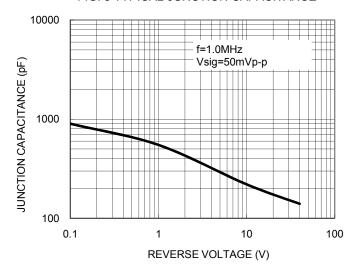
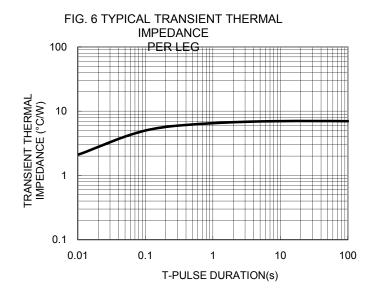




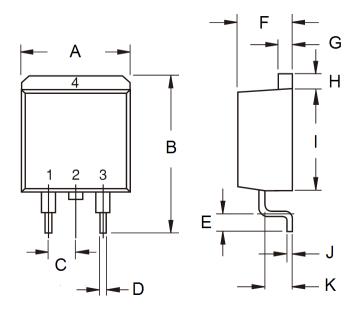


FIG. 5 TYPICAL JUNCTION CAPACITANCE



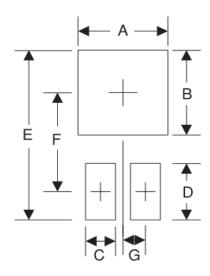


PACKAGE OUTLINE DIMENSIONS TO-263AB (D²PAK)



DIM.	Unit	(mm)	Unit (inch)		
DIW.	Min	Max	Min	Max	
Α	-	10.5	-	0.413	
В	14.60	15.88	0.575	0.625	
С	2.41	2.67	0.095	0.105	
D	0.68	0.94	0.027	0.037	
Е	2.29	2.79	0.090	0.110	
F	4.44	4.70	0.175	0.185	
G	1.14	1.40	0.045	0.055	
Н	1.14	1.40	0.045	0.055	
I	8.25	9.25	0.325	0.364	
J	0.36	0.53	0.014	0.021	
K	2.03	2.79	0.080	0.110	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	10.8	0.425
В	8.3	0.327
С	1.1	0.043
D	3.5	0.138
Е	16.9	0.665
F	9.5	0.374
G	2.5	0.098

MARKING DIAGRAM



P/N = Specific Device Code
G = Green Compound
YWW = Date Code

F = Factory Code



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